

Gate Trigger Current

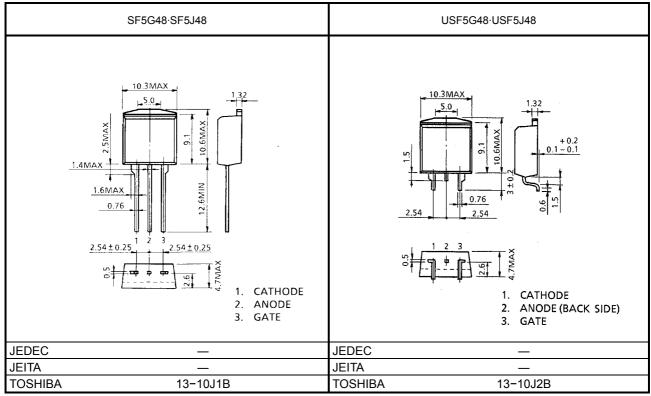
#### TOSHIBA THYRISTOR SILICON PLANAR TYPE

# SF5G48,SF5J48,USF5G48,USF5J48

#### MEDIUM POWER CONTROL APPLICATIONS

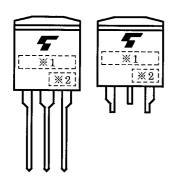
• Repetitive Peak Off-State Voltage: VDRM = 400, 600V Repetitive Peak Reverse Voltage  $: V_{RRM} = 400, 600V$ Average On-State Current  $: I_{T}(AV) = 5A$ : IGT = 10mA Max.

Unit: mm



Weight: 1.7g

#### **MARKING**



*1	MARK	F5G48	TYPE	SF5G48, USF5G48			
		F5J48	NAME	SF5J48, USF5J48			
	Lot Number						
*2	Month (Starting from Alphabet A) Year (Last Decimal Digit of the						
	Current Year)						



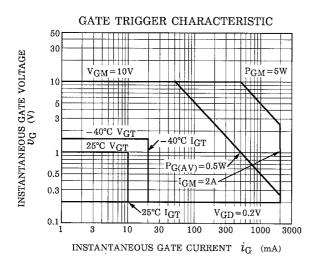
### **MAXIMUM RATINGS**

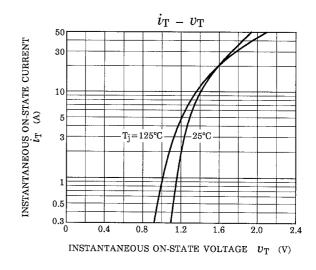
CHARACTERI	SYMBOL	RATING	UNIT		
	SF5G48		400		
Repetitive Peak Off-State Voltage	USF5G48	V <sub>DRM</sub> V <sub>RRM</sub>	400	V	
and Repetitive Peak Reverse Voltage	SF5J48		600		
	USF5J48		000		
	SF5G48		500		
Non-Repetitive Peak Reverse Voltage	USF5G48	\/pau	300	V	
(Non-Repetitive < 5ms $T_i = 0 \sim 125^{\circ}C$ )	SF5J48	V <sub>RSM</sub>	720		
	USF5J48		720		
Average On-State Curre	I <sub>T (AV)</sub>	5	Α		
R.M.S On-State Current		I <sub>T (RMS)</sub>	7.8	Α	
Peak One Cycle Surge On-State Current (Non-Repetitive)		I <sub>TSM</sub>	80 (50Hz)	А	
			88 (60Hz)	, ,	
I <sup>2</sup> t Limit Value		I <sup>2</sup> t	32	A <sup>2</sup> s	
Critical Rate of Rise of On-State Current	di /dt	100	A/µs		
Peak Gate Power Dissip	ation	$P_{GM}$	5	W	
Average Gate Power Dissition		P <sub>G (AV)</sub>	0.5	W	
Peak Forward Gate Volt	age	$V_{FGM}$	10	V	
Peak Reverse Gate Voltage		$V_{RGM}$	<b>-</b> 5	V	
Peak Forward Gate Curr	ent	$I_{GM}$	2	А	
Junction Temperature		Tj	-40~125	°C	
Strage Temperature Rai	nge	T <sub>stg</sub>	-40~125	°C	

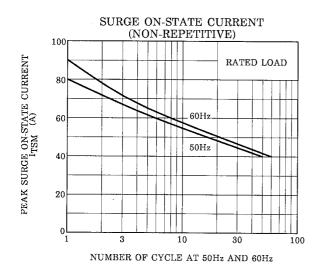
Note 1:  $V_{DRM} = 0.5 \times Rated$   $I_{TM} \le 15A$   $t_{gw} \ge 10\mu s$   $t_{gr} \le 250ns$  $i_{gp} = I_{GT} \times 2.0$ 

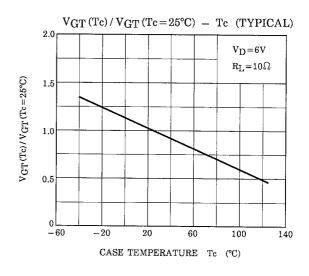
## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

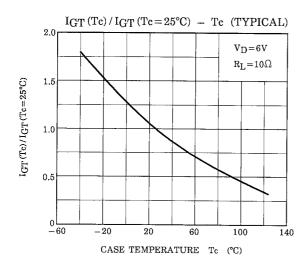
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse	I <sub>DRM</sub> I <sub>RRM</sub>	V <sub>DRM</sub> = V <sub>RRM</sub> = Rated	_	_	10	μΑ
Peak On-State Voltage	$V_{TM}$	I <sub>TM</sub> = 15A	_	_	1.5	V
Gate Trigger Voltage	V <sub>GT</sub>	V = 6V B = 100	_	_	1.0	V
Gate Trigger Current	I <sub>GT</sub>	$V_D = 6V, R_L = 10\Omega$	_	_	10	mA
Gate Non-Trigger Voltage	$V_{GD}$	V <sub>D</sub> = Rated × 2 / 3, Tc = 125°C	0.2	_	_	V
Critical Rate of Rise of Off-State Voltage	dv / dt	V <sub>DRM</sub> = Rated, Tc = 125°C Exponential Rise	_	50	_	V / µs
Holding Current	I <sub>H</sub>	V <sub>D</sub> = 6V, I <sub>TM</sub> = 1A	_	_	40	mA
Latching Current	ΙL	$V_D = 6V, f = 50Hz$ $t_{gw} = 50\mu s, i_G = 30mA$	_	_	50	mA
Thermal Resistance	R <sub>th (j-c)</sub>	Junction to Case, DC	_	_	3.2	°C/W

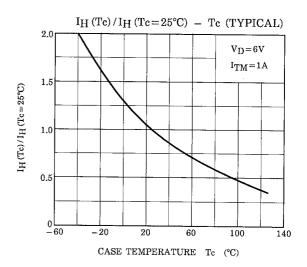


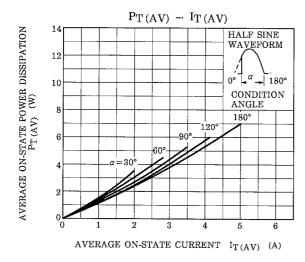


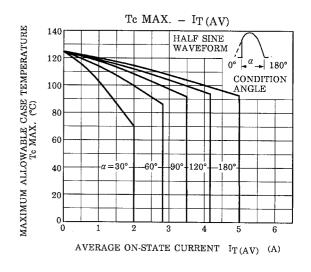


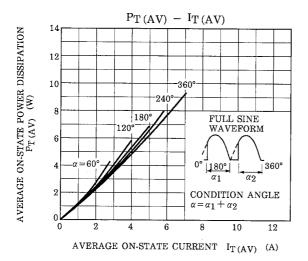


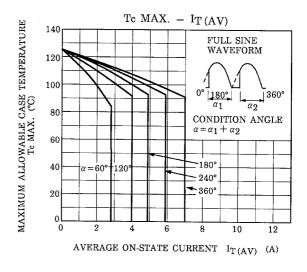


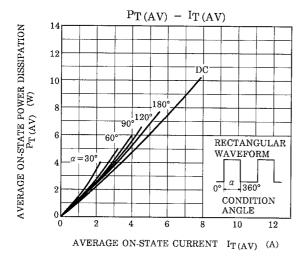


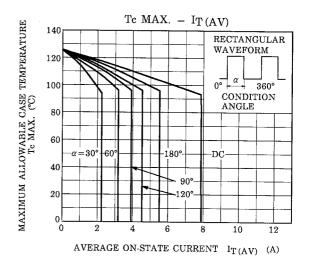




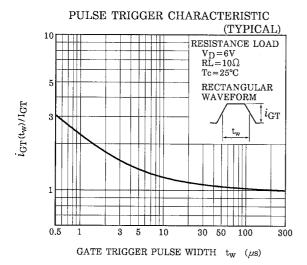


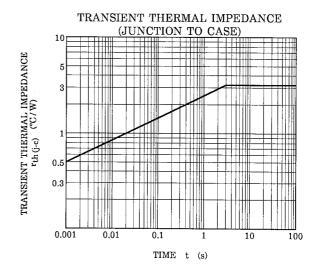














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